Electron and hole g factor anisotropy in CdTe/CdMgTe quantum wells

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Abstract

Effective g factors of electrons and heavy holes in CdTe/CdMgTe quantum wells have been measured with high accuracy as a function of the angle between the magnetic field and the structure growth axis. As a result, we have observed the electron g factor anisotropy in A3B5-based heterostructures. The dependences of the g factor tensor components on the quantum-well width and the solid solution composition have been calculated within the k·p method and compared with the available experimental data. © 1998 Elsevier Science B.V. All rights reserved.

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A precise knowledge of g factors is important for the interpretation of magneto-optics, magneto-transport, resonant spectroscopy on spin-split sublevels, and light-scattering experiments. Various experimental techniques have been applied to study exciton and free-carrier g factors in semiconductor heterostructures (see Ref. [1] and references therein). Nevertheless, the experimental data base for electron and hole g factors in low-dimensional systems is far from being complete and limited predominantly to the A3B5 heterostructures. Only very recently, g factors in narrow (20–100 Å) and wide (80–300 Å) CdTe/CdMgTe quantum wells (QWs) have been measured by means of resonant spin-flip Raman scattering (SFRS) [1] and quantum-beat spectroscopy and photoluminescence (PL) [2], respectively.

In this paper we focus on the comparison of calculations of the electron and hole g factors with experimental data obtained by SFRS, which has been proven to be one of the most reliable experimental techniques for the direct determination of g factors in low-dimensional systems. The components of the g factor tensor are calculated in the
framework of the $k \cdot p$ theory for both electrons and holes as a function of layer width and solid solution composition. Effects of the strain (induced by the lattice-constant mismatch) on the $g$ factor values are analysed and compared to the size-confinement effects.

CdTe/CdMgTe heterostructures with type-I band alignment were grown by molecular-beam epitaxy on (0 0 1)-oriented CdTe and Cd$_{0.97}$Zn$_{0.03}$Te substrates. CdTe single QWs with widths between 18 and 100 Å are sandwiched between Cd$_{1-x}$Mg$_x$Te barriers with $x = 0.15$, 0.26 and 0.5. Further information about the sample parameters, their characterisation and the experimental set-up has been published elsewhere [1].

In a magnetic field we observe two narrow Stokes (and anti-Stokes) SFRS lines for excitation in resonance with the heavy-hole exciton transition. These lines are attributed to exciton and electron spin-flip processes. The spin-flip shifts of the electron and exciton lines, $\Delta_{ex}$ and $\Delta_{e}$, are proportional to the magnetic field, $B$. Since the exchange splittings of the exciton levels at $B = 0$ are small compared to the observed Zeeman splittings and can be disregarded hereafter, $\Delta_{ex}$ and $\Delta_{e}$ are proportional to the exciton and electron $g$ factors (see Ref. [1] for discussion about the $g$ factor signs). The heavy-hole $g$ factor is determined by the relation $g^h = g^e + g^c$. In the magnetic field making an angle $\varphi$ with the QW growth axis,

$$|g^{e,h}(\varphi)| = \sqrt{(g^{e,h} \cos \varphi)^2 + (g^{e,h} \sin \varphi)^2}.$$ 

The $g$ factor components were obtained from the fit of this equation to the experimental angle dependences.

Values of both electron $g$ factor components for a series of single-QW structures CdTe/Cd$_{1-x}$Mg$_x$Te with $x = 0.15$ are shown in Fig. 1 by solid $(g\parallel)$ and open $(g\perp)$ squares. We have also included in this graph the results on transverse $g$ factor measurements [2] (circles, $x = 0.25$) which considerably extend the range of QW widths available for the comparison with theory.

In order to calculate the electron $g$ factor we apply the Kane model. Thus, the $k_xp_x$ mixing between $\Gamma_6$, $\Gamma_8^x$ and $\Gamma_7^x$ is taken into account exactly. The $k_xp_x$ and $k_yp_y$ terms are treated by second-order perturbation theory, which is sufficient for the $g$ factor calculation [3]. For the conduction sub-band $e_1$, the $g$ factor components are given by [3]

$$g_{\parallel} = g_0f_{\parallel} + \frac{1}{m_0} \sum_n \langle \langle e_{1,1/2}|p_+|n\rangle \rangle^2$$

$$- |\langle e_{1,1/2}|p_-|n\rangle \rangle^2 \frac{1}{E_{e_1} - E_n^0},$$

$$g_{\perp} = g_0f_{\perp} - \frac{2}{m_0} \sum_n \text{Re}(\langle e_{1,1/2}|p_-|n\rangle \rangle^2$$

$$\langle n|p_x|e_1, -1/2\rangle \rangle \frac{1}{E_{e_1} - E_n^0}. \quad (1)$$

Here $m_0$, $g_0$ are the free-electron mass and Lande factor, $p_{\pm} = p_x \pm ip_y$, $\langle n|p_x|m\rangle (x = x, y, z)$ is the
momentum operator matrix element taken, in a single-QW structure, between the sub-band states \( n, m \) at the extremum \( k_x = k_y = 0 \) and, in a superlattice, between the miniband states \( n, m \) at \( k_x = k_y = Q = 0 \), where \( Q \) is the wave vector component describing the electron motion along \( z \). \( E_n^0 \) is the electron energy at this point. The coefficients \( f_{||}, f_{\perp} \) are close to unity and take into account that the average spin component for an electron in the state \( |e_1, \pm \frac{1}{2}\rangle \) differs slightly from \( \pm 1/2 \) even at the extremum because of the \( k_xp_x \)-induced mixing with valence-band states.

The lattice mismatch between zinc-blende MgTe and CdTe is 1.0%. Shifts of the CdTe conduction and valence-band edges due to the strain are included in the calculation procedure. We assume the barrier material to be unstrained which is valid in the case of thick barrier layers. Thus, the heavy- and light-hole states in the CdTe/CdMgTe QWs are split due to both confinement and stress caused by the lattice mismatch between the compositional materials. In the CdTe/CdMgTe heterosystem, these two effects act in the same direction and push the light-hole states towards higher energies.

The solid (dotted) lines in Fig. 1 show calculated dependences of \( g_{||}^{\text{hh}} \) and \( g_{\perp}^{\text{hh}} \) on the well width for CdTe/Cd\(_{1-x}\)Mg\(_x\)Te QW with \( x = 0.15 \) (0.26). The band parameters used in the calculation are as follows: the band gap \( E_g(x) = 1.606 + 1.755x \) eV for bulk Cd\(_{1-x}\)Mg\(_x\)Te, the spin-orbit splitting of the valence band \( \Delta = 0.93 \) eV and the parameter \( 2p_{cv}/m_0 = 21 \) eV (\( p_{cv} \) is the interband matrix element \( i \langle S|p_z|Z\rangle \)) are assumed to be independent of \( x \), the valence band offset \( \Delta E_v \) is 30\% of the difference in the barrier and well band gaps.

A small fixed contribution of remote bands has been added to Eq. (1). This allows us to get in the calculations (neglecting the strain) values of \( g_{||}^{\text{hh}} \) and \( g_{\perp}^{\text{hh}} \) which in the limit of very thick QWs are close to \(-1.64 \) (\( g \) factor in bulk CdTe) and, at the same time, for ultra-thin QWs tend to \(-0.80 \) (\( g \) factor in bulk Cd\(_{0.85}\)Mg\(_{0.15}\)Te). One can see from Fig. 1 that the theory is in a rather good agreement with experiment despite the absence of other fitting parameters.

The experimentally measured electron \( g \) factor anisotropy, \( (g_{||}^{\text{eh}} - g_{\perp}^{\text{eh}}) \), as a function of the QW width is presented by squares in the inset of Fig. 1.

The reduction of the system symmetry due to uniaxial strain and spatial confinement leads to the \( g \) factor anisotropy as well as to the splitting of the \( \Gamma_8 \) band into the light- and heavy-hole sub-bands. The \( g \)-factor anisotropy exhibits non-monotonic behaviour and, for CdTe/Cd\(_{0.85}\)Mg\(_{0.15}\)Te QW structures, reaches a maximum for well widths \( \sim 40 \) \AA.

The electron \( g \) factor anisotropy is a continuous function of the QW width and vanishes for widths very large or close to zero. In contrast, the strong heavy-hole \( g \) factor anisotropy, \( |g_{||}^{\text{hh}}| >> |g_{\perp}^{\text{hh}}| \), appears as soon as the degeneracy between the heavy and light-hole states is lifted. The measured angle dependence of the heavy-hole \( g \) factor confirms that the value of \( g_{||}^{\text{hh}} \) is close to zero. For the samples with \( x = 0.15 \), the longitudinal component is shown in Fig. 2 as a function of the well width (squares). The sum \( (g_{||}^{\text{hh}} + g_{\perp}^{\text{hh}}) \) found from Ref. [2] is presented by
circles. It can serve as a good estimate of \( g_{\|}^\text{hh} \). The uncertainty connected with the electron \( g \) factor anisotropy lies within the accuracy of the exciton \( g \) factor determination from the Zeeman splittings of the exciton transitions in PL and transmission experiments [2].

The simple Kane model which exactly takes into account the \( k \cdot p \) interaction of the \( \Gamma_6^\varepsilon, \Gamma_8^\varepsilon, \) and \( \Gamma_7^\varepsilon \) bands is insufficient for calculations of heavy-hole properties. In particular, it yields a negative heavy-hole effective mass \( m_{\text{hh}} = - m_0 \). As is well known, a positive value of \( m_{\text{hh}} \) arises due to the \( k \cdot p \) contribution of the remote conduction bands \( \Gamma_6^\varepsilon + \Gamma_8^\varepsilon \). We use in the heavy-hole \( g \) factor calculations the complete \( 8 \times 8 \) \( k \cdot p \) Hamiltonian which has advantages compared to the Kane model since it describes completely the coupling between the \( \Gamma_6^\varepsilon, \Gamma_8^\varepsilon, \) and \( \Gamma_7^\varepsilon \) bands and includes the contributions of the remote bands in an approximation i.e. the quadratic in \( k \) [4].

The solid (dotted) line in Fig. 2 shows a calculation of \( g_{\|}^\text{hh} \) for \( x = 0.15 \) (0.26). Since the band parameters for \( \text{A}_2\text{B}_6 \) semiconductors are known to a much less extent than those for \( \text{A}_3\text{B}_5 \) compounds, a simple fitting procedure has been carried out to find the Luttinger parameters for CdTe. Using the spherical approximation \( (\gamma_2^L - \gamma_3^L) \) and neglecting contributions of remote bands with \( \Gamma_4 \) symmetry, one finds

\[
k^L = \frac{1}{3} (2\gamma_2^L + 3\gamma_3^L - \gamma_1^L - 2).
\]

We applied this procedure to the set of experimental data for the samples with \( x = 0.15 \) and obtained the following Luttinger parameters:

\[
\gamma_1^L = 5.1, \gamma_2^L \equiv \gamma_3^L = 1.66, k^L = 0.4.
\]

In Fig. 2 the dotted line (\( x = 0.26 \)) is plotted with the same set of \( \gamma_1^L, k^L \).

In summary, by resonant SFRS we have measured with high accuracy the electron, exciton and heavy-hole \( g \) factors in CdTe/CdMgTe QWs. We developed a theory which takes the complicated valence-band structure as well as quantum-confinement and strain-induced effects into account. It provides a consistent description of the observed \( g \) factors as a function of the QW width.

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References